1 Features

- 20 to 1 Frequency Range With an External Resistor
- Logic Compatible Output With 100-mA Current Sinking Capability
- Bandwidth Adjustable From 0 to 14%
- High Rejection of Out of Band Signals and Noise
- Immunity to False Signals
- Highly Stable Center Frequency
- Center Frequency Adjustable from 0.01 Hz to 500 kHz

2 Applications

- Touch Tone Decoding
- Precision Oscillator
- Frequency Monitoring and Control
- Wide Band FSK Demodulation
- Ultrasonic Controls
- Carrier Current Remote Controls
- Communications Paging Decoders

3 Description

The LM567 and LM567C are general purpose tone decoders designed to provide a saturated transistor switch to ground when an input signal is present within the passband. The circuit consists of an I and Q detector driven by a voltage controlled oscillator which determines the center frequency of the decoder. External components are used to independently set center frequency, bandwidth and output delay.

4 Simplified Diagram

---

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.
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5 Revision History
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Changes from Revision D (March 2013) to Revision E .............................. 1

   • Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section .......................... 1

Changes from Revision C (March 2013) to Revision D ............................... 9

   • Changed layout of National Data Sheet to TI format ................................................................. 9
6 Device Comparison Table

<table>
<thead>
<tr>
<th>DEVICE NAME</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM567, LM567C</td>
<td>General Purpose Tone Decoder</td>
</tr>
<tr>
<td>LMC567</td>
<td>Same as LM567C, but lower power supply current consumption and double oscillator frequency</td>
</tr>
</tbody>
</table>

7 Pin Configuration and Functions

### Pin Configuration and Functions

8-Pin PDIP (P) and SOIC (D) Package

**Top View**

- **Pin Functions**

<table>
<thead>
<tr>
<th>PIN</th>
<th>TYPE</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>GND</td>
<td>7</td>
<td>P</td>
</tr>
<tr>
<td>IN</td>
<td>3</td>
<td>I</td>
</tr>
<tr>
<td>LF_CAP</td>
<td>2</td>
<td>I</td>
</tr>
<tr>
<td>OUT</td>
<td>8</td>
<td>O</td>
</tr>
<tr>
<td>OF_CAP</td>
<td>1</td>
<td>I</td>
</tr>
<tr>
<td>T_CAP</td>
<td>5</td>
<td>I</td>
</tr>
<tr>
<td>T_RES</td>
<td>6</td>
<td>I</td>
</tr>
<tr>
<td>VCC</td>
<td>4</td>
<td>P</td>
</tr>
</tbody>
</table>
8 Specifications

8.1 Absolute Maximum Ratings\(^{(1)}\)(\(^{(2)}\))(\(^{(3)}\))

<table>
<thead>
<tr>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>9</td>
<td>15</td>
<td>V</td>
</tr>
<tr>
<td>-10</td>
<td>10</td>
<td>V</td>
</tr>
<tr>
<td>0</td>
<td>70</td>
<td>°C</td>
</tr>
</tbody>
</table>

8.2 Recommended Operating Conditions

<table>
<thead>
<tr>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>3.5</td>
<td>8.5</td>
<td>V</td>
</tr>
<tr>
<td>-8.5</td>
<td>8.5</td>
<td>V</td>
</tr>
<tr>
<td>-20</td>
<td>120</td>
<td>°C</td>
</tr>
</tbody>
</table>

8.3 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC(^{(1)})</th>
<th>LM567C</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>D</td>
<td>P</td>
</tr>
<tr>
<td>R(_{JA})</td>
<td>107.5</td>
<td>53.0</td>
</tr>
<tr>
<td>R(_{JC(top)})</td>
<td>54.6</td>
<td>42.3</td>
</tr>
<tr>
<td>R(_{JB})</td>
<td>47.5</td>
<td>30.2</td>
</tr>
<tr>
<td>(\psi_{JT})</td>
<td>10.0</td>
<td>19.6</td>
</tr>
<tr>
<td>(\psi_{JB})</td>
<td>47.0</td>
<td>30.1</td>
</tr>
</tbody>
</table>

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended Operating Conditions indicate conditions for which the device is functional, but do not ensure specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Recommended Operating Conditions. Specifications are not ensured for parameters where no limit is given, however, the typical value is a good indication of device performance.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

(3) See [http://www.ti.com](http://www.ti.com) for other methods of soldering surface mount devices.

(4) The maximum junction temperature of the LM567 and LM567C is 150°C. For operating at elevated temperatures, devices in the DIP package must be derated based on a thermal resistance of 110°C/W, junction to ambient. For the SOIC package, the device must be derated based on a thermal resistance of 160°C/W, junction to ambient.

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
## 8.4 Electrical Characteristics

AC Test Circuit, $T_A = 25^\circ C$, $V^+ = 5 V$

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>LM567</th>
<th>LM567C/LM567CM</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Power Supply Voltage Range</td>
<td></td>
<td>4.75</td>
<td>5.0</td>
<td>9.0</td>
</tr>
<tr>
<td>Power Supply Current Quiescent</td>
<td>$R_L = 20k$</td>
<td>6</td>
<td>8</td>
<td>7</td>
</tr>
<tr>
<td>Power Supply Current Activated</td>
<td>$R_L = 20k$</td>
<td>11</td>
<td>13</td>
<td>12</td>
</tr>
<tr>
<td>Input Resistance</td>
<td></td>
<td>18</td>
<td>20</td>
<td>15</td>
</tr>
<tr>
<td>Smallest Detectable Input Voltage</td>
<td>$I_L = 100 mA, f_i = f_o$</td>
<td>20</td>
<td>25</td>
<td>20</td>
</tr>
<tr>
<td>Largest No Output Input Voltage</td>
<td>$I_C = 100 mA, f_i = f_o$</td>
<td>10</td>
<td>15</td>
<td>10</td>
</tr>
<tr>
<td>Largest Simultaneous Outband Signal to</td>
<td></td>
<td>6</td>
<td>6</td>
<td></td>
</tr>
<tr>
<td>Inband Signal Ratio</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Minimum Input Signal to Wideband Noise</td>
<td>$B_n = 140 kHz$</td>
<td>−6</td>
<td>−6</td>
<td></td>
</tr>
<tr>
<td>Ratio</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Largest Detection Bandwidth</td>
<td></td>
<td>12</td>
<td>14</td>
<td>16</td>
</tr>
<tr>
<td>Largest Detection Bandwidth Skew</td>
<td></td>
<td>1</td>
<td>2</td>
<td>2</td>
</tr>
<tr>
<td>Largest Detection Bandwidth Variation</td>
<td></td>
<td>±0.1</td>
<td>±0.1</td>
<td></td>
</tr>
<tr>
<td>with Temperature</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Largest Detection Bandwidth Variation</td>
<td>4.75 – 6.75 V</td>
<td>±1</td>
<td>±2</td>
<td>±1</td>
</tr>
<tr>
<td>with Supply Voltage</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Highest Center Frequency</td>
<td></td>
<td>100</td>
<td>500</td>
<td>100</td>
</tr>
<tr>
<td>Center Frequency Stability (4.75 – 5.75 V)</td>
<td></td>
<td>35 ± 60</td>
<td>35 ± 140</td>
<td>35 ± 60</td>
</tr>
<tr>
<td>Center Frequency Shift with Supply Voltage</td>
<td>4.75 V – 6.75 V</td>
<td>0.5</td>
<td>1.0</td>
<td>0.4</td>
</tr>
<tr>
<td></td>
<td>4.75 V – 9 V</td>
<td>2.0</td>
<td></td>
<td>2.0</td>
</tr>
<tr>
<td>Fastest ON-OFF Cycling Rate</td>
<td></td>
<td>$f_o/20$</td>
<td>$f_o/20$</td>
<td></td>
</tr>
<tr>
<td>Output Leakage Current</td>
<td>$V_8 = 15 V$</td>
<td>0.01</td>
<td>25</td>
<td>0.01</td>
</tr>
<tr>
<td>Output Saturation Voltage</td>
<td>$e_i = 25 mV, I_B = 30 mA$</td>
<td>0.2</td>
<td>0.4</td>
<td>0.2</td>
</tr>
<tr>
<td></td>
<td>$e_i = 25 mV, I_B = 100 mA$</td>
<td>0.6</td>
<td>1.0</td>
<td>0.6</td>
</tr>
<tr>
<td>Output Fall Time</td>
<td></td>
<td>30</td>
<td>30</td>
<td></td>
</tr>
<tr>
<td>Output Rise Time</td>
<td></td>
<td>150</td>
<td>150</td>
<td></td>
</tr>
</tbody>
</table>
8.5 Typical Characteristics

Figure 1. Typical Frequency Drift

Figure 2. Typical Bandwidth Variation

Figure 3. Typical Frequency Drift

Figure 4. Typical Frequency Drift

Figure 5. Bandwidth vs Input Signal Amplitude

Figure 6. Largest Detection Bandwidth
Typical Characteristics (continued)

Figure 7. Detection Bandwidth as a Function of $C_2$ and $C_3$

Figure 8. Typical Supply Current vs Supply Voltage

Figure 9. Greatest Number of Cycles Before Output

Figure 10. Typical Output Voltage vs Temperature
9 Parameter Measurement Information

All parameters are measured according to the conditions described in the Specifications section.

10 Detailed Description

10.1 Overview

The LM567C is a general purpose tone decoder. The circuit consists of I and Q detectors driven by a voltage controlled oscillator which determines the center frequency of the decoder. This device is designed to provide a transistor switch to ground output when the input signal frequency matches the center frequency pass band. Center frequency is set by an external timing circuit composed by a capacitor and a resistor. Bandwidth and output delay are set by external capacitors.

10.2 Functional Block Diagram
10.3 Feature Description

10.3.1 Center Frequency
The center frequency of the LM567 tone decoder is equal to the free running frequency of the voltage controlled oscillator. In order to set this frequency, external components should be placed externally. The component values are given by:

\[ f_0 \approx \frac{1.1}{R_1 C_1} \]

where
- \( R_1 \) = Timing Resistor
- \( C_1 \) = Timing Capacitor

(1)

10.3.2 Output Filter
To eliminate undesired signals that could trigger the output stage, a post detection filter is featured in the LM567C. This filter consists of an internal resistor (4.7K-Ω) and an external capacitor. Although typically external capacitor value is not critical, it is recommended to be at least twice the value of the loop filter capacitor. If the output filter capacitor value is too large, the turn-on and turn-off time of the output will present a delay until the voltage across this capacitor reaches the threshold level.

10.3.3 Loop Filter
The phase locked loop (PLL) included in the LM567 has a pin for connecting the low pass loop filter capacitor. The selection of the capacitor for the filter depends on the desired bandwidth. The device bandwidth selection is different according to the input voltage level. Refer to the Operation With \( V_i < 200m – \overline{V}_{RMS} \) section and the Operation With \( V_i > 200m – \overline{V}_{RMS} \) section for more information about the loop filter capacitor selection.

10.3.4 Logic Output
The LM567 is designed to provide a transistor switch to ground output when the input signal frequency matches the center frequency pass band. The logic output is an open collector power transistor that requires an external load resistor that is used to regulate the output current level.

10.3.5 Die Characteristics

![Die Layout (C - Step)](image-url)

Figure 11. Die Layout (C - Step)
Feature Description (continued)

Table 1. Die and Wafer Characteristics

<table>
<thead>
<tr>
<th>Fabrication Attributes</th>
<th>General Die Information</th>
</tr>
</thead>
<tbody>
<tr>
<td>Physical Die Identification</td>
<td>LM567C</td>
</tr>
<tr>
<td>Die Step</td>
<td>C</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th>Physical Attributes</th>
<th>Passivation</th>
<th>VOM NITRIDE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Wafer Diameter</td>
<td>150mm</td>
<td>Back Side Metal</td>
</tr>
<tr>
<td>Die Size (Drawn)</td>
<td>1600µm x 1626µm</td>
<td>Back Side Connection</td>
</tr>
<tr>
<td>Thickness</td>
<td>406µm Nominal</td>
<td></td>
</tr>
<tr>
<td>Min Pitch</td>
<td>198µm Nominal</td>
<td></td>
</tr>
</tbody>
</table>

Special Assembly Requirements:

Note: Actual die size is rounded to the nearest micron.

Die Bond Pad Coordinate Locations (C - Step)

<table>
<thead>
<tr>
<th>SIGNAL NAME</th>
<th>PAD# NUMBER</th>
<th>X/Y COORDINATES</th>
<th>PAD SIZE</th>
</tr>
</thead>
<tbody>
<tr>
<td>OUTPUT FILTER</td>
<td>1</td>
<td>-673 686 91 x 91</td>
<td>104</td>
</tr>
<tr>
<td>LOOP FILTER</td>
<td>2</td>
<td>-673 -419 91 x 91</td>
<td>104</td>
</tr>
<tr>
<td>INPUT</td>
<td>3</td>
<td>-673 -686 91 x 91</td>
<td>104</td>
</tr>
<tr>
<td>V+</td>
<td>4</td>
<td>-356 -686 91 x 91</td>
<td>104</td>
</tr>
<tr>
<td>TIMING RES</td>
<td>5</td>
<td>673 -122 91 x 91</td>
<td>104</td>
</tr>
<tr>
<td>TIMING CAP</td>
<td>6</td>
<td>673 76 91 x 91</td>
<td>104</td>
</tr>
<tr>
<td>GND</td>
<td>7</td>
<td>178 686 117 x 104</td>
<td>104</td>
</tr>
<tr>
<td>OUTPUT</td>
<td>8</td>
<td>-318 679 117 x 104</td>
<td>104</td>
</tr>
</tbody>
</table>

10.4 Device Functional Modes

10.4.1 Operation With \( V_i < 200m – V_{RMS} \)

When the input signal is below a threshold voltage, typically 200m-VRMS, the bandwidth of the detection band should be calculated:

\[
BW = 1070 \left( \frac{V_i}{f_0 C_2} \right)^{1/2} \text{ in } \% \text{ of } f_0
\]

where

- \( V_i \) = Input voltage (volts rms), \( V_i \leq 200mV \)
- \( C_2 \) = Capacitance at Pin 2(µF)
Device Functional Modes (continued)

10.4.2 Operation With $V_i > 200m - V_{RMS}$

For input voltages greater than 200m-VRMS, the bandwidth depends directly from the loop filter capacitance and free running frequency product. Bandwidth is represented as a percentage of the free running frequency, and according to the product of $f_0\cdot C_2$, it can have a variation from 2 to 14%. Table 2 shows the approximate values for bandwidth in function of the product result.

Table 2. Detection Bandwidth in Function of $f_0 \times C_2$

<table>
<thead>
<tr>
<th>$f_0 \times C_2$ (kHzµF)</th>
<th>Bandwidth (% of $f_0$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>62</td>
<td>2</td>
</tr>
<tr>
<td>16</td>
<td>4</td>
</tr>
<tr>
<td>7.3</td>
<td>6</td>
</tr>
<tr>
<td>4.1</td>
<td>8</td>
</tr>
<tr>
<td>2.6</td>
<td>10</td>
</tr>
<tr>
<td>1.8</td>
<td>12</td>
</tr>
<tr>
<td>1.3</td>
<td>14</td>
</tr>
<tr>
<td>&lt; 1.3</td>
<td>14</td>
</tr>
</tbody>
</table>
11 Application and Implementation

NOTE
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

11.1 Application Information
The LM567 tone decoder is a device capable of detecting if an input signal is inside a selectable range of detection. The device has an open collector transistor output, so an external resistor is required to achieve proper logic levels. When the input signal is inside the detection band, the device output will go to a LOW state. The internal VCO free running frequency establishes the detection band central frequency. An external RC filter is required to set this frequency. The bandwidth in which the device will detect the desired frequency depends on the capacitance of loop filter terminal. Typically a 1µF capacitor is connected to this pin. The device detection band has a different behavior for low and high input voltage levels. Refer to the Operation With $V_i < 200m - V_{RMS}$ section and the Operation With $V_i > 200m - V_{RMS}$ section for more information.
11.2 Typical Applications

11.2.1 Touch-Tone Decoder

Component values (typ)
R1 6.8 to 15k
R2 4.7k
R3 20k
C1 0.10 mfd
C2 1.0 mfd 6V
C3 2.2 mfd 6V
C4 250 mfd 6V

Figure 12. Touch-Tone Decoder

11.2.1.1 Design Requirements

<table>
<thead>
<tr>
<th>PARAMETERS</th>
<th>VALUES</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage Range</td>
<td>3.5 V to 8.5 V</td>
</tr>
<tr>
<td>Input Voltage Range</td>
<td>20 mVRMS to VCC + 0.5</td>
</tr>
<tr>
<td>Input Frequency</td>
<td>1 Hz to 500 kHz</td>
</tr>
<tr>
<td>Output Current</td>
<td>Max. 15 mA</td>
</tr>
</tbody>
</table>
11.2.1.2 Detailed Design Procedure

11.2.1.2.1 Timing Components
To calculate the timing components for an approximated desired central detection frequency \( f_0 \), the timing capacitor value \( C_1 \) should be stated in order to calculate the timing resistor value \( R_1 \). Typically for most applications, a 0.1-\( \mu \)F capacitor is used.

\[
f_0 \approx \frac{1.1}{R_1C_1}
\]  
(2)

11.2.1.2.2 Bandwidth
Detection bandwidth is represented as a percentage of \( f_0 \). It can be selected based on the input voltage levels \( V_i \). For \( V_i < 200 \text{ mV}_{\text{RMS}} \),

\[
\text{BW} = 1070 \sqrt{\frac{V_i}{f_0C_2}} \text{ in } \% \text{ of } f_0
\]  
(3)

For \( V_i > 200 \text{ mV}_{\text{RMS}} \), refer to Table 2 or Figure 5.

11.2.1.2.3 Output Filter
The output filter selection is made considering the capacitor value to be at least twice the Loop filter capacitor.

\[
C_3 \geq 2C_2
\]  
(4)

11.2.1.3 Application Curve

![Figure 13. Frequency Detection](image-url)
11.2.2 Oscillator with Quadrature Output

Connect Pin 3 to 2.8V to Invert Output

Figure 14. Oscillator with Quadrature Output

11.2.2.1 Design Requirements
Refer to the previous Design Requirements section.

11.2.2.2 Detailed Design Procedure
Refer to the previous Detailed Design Procedure section.

11.2.2.3 Application Curve

Figure 15. Quadrature Output
11.2.3 Oscillator with Double Frequency Output

11.2.3.1 Design Requirements
Refer to the previous Design Requirements section.

11.2.3.2 Detailed Design Procedure
Refer to the previous Detailed Design Procedure section.

11.2.3.3 Application Curve

Figure 16. Oscillator with Double Frequency Output

Figure 17. Double Frequency Output
11.2.4 Precision Oscillator Drive 100-mA Loads

11.2.4.1 Design Requirements
Refer to the previous Design Requirements section.

11.2.4.2 Detailed Design Procedure
Refer to the previous Detailed Design Procedure section.

11.2.4.3 Application Curve

Figure 18. Precision Oscillator Drive 100-mA Loads

Figure 19. Output for 100-mA Load
11.2.5 AC Test Circuit

\[ f_i = 100 \text{ kHz} + 5 \text{ V} \]

*Note: Adjust for \( f_o = 100 \text{ kHz} \).

11.2.5.1 Design Requirements
Refer to the previous Design Requirements section.

11.2.5.2 Detailed Design Procedure
Refer to the previous Detailed Design Procedure section.

11.2.5.3 Application Curve
Refer to the previous Application Curve section.
12 Power Supply Recommendations

The LM567C is designed to operate with a power supply up to 9 V. It is recommended to have a well regulated power supply. As the operating frequency of the device could be very high for some applications, the decoupling of power supply becomes critical, so is required to place a proper decoupling capacitor as close as possible to VCC pin.

13 Layout

13.1 Layout Guidelines

The VCC pin of the LM567 should be decoupled to ground plane as the device can work with high switching speeds. The decoupling capacitor should be placed as close as possible to the device. Traces length for the timing and external filter components should be kept at minimum in order to avoid any possible interference from other close traces.

13.2 Layout Example

![Layout Example Diagram](image)
14 Device and Documentation Support

14.1 Related Links
The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

<table>
<thead>
<tr>
<th>PARTS</th>
<th>PRODUCT FOLDER</th>
<th>SAMPLE &amp; BUY</th>
<th>TECHNICAL DOCUMENTS</th>
<th>TOOLS &amp; SOFTWARE</th>
<th>SUPPORT &amp; COMMUNITY</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM567</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
</tr>
<tr>
<td>LM567C</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
</tr>
</tbody>
</table>

14.2 Trademarks
All trademarks are the property of their respective owners.

14.3 Electrostatic Discharge Caution
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

14.4 Glossary

SLYZ022 — *TI Glossary.*
This glossary lists and explains terms, acronyms, and definitions.

15 Mechanical, Packaging, and Orderable Information
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
## PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>PINS</th>
<th>Package Qty</th>
<th>Eco Plan</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp</th>
<th>Op Temp (°C)</th>
<th>Device Marking</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM567CM/NOPB</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>95</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU SN</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>LM 567CM</td>
<td>Samples</td>
</tr>
<tr>
<td>LM567CMX/NOPB</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU SN</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>LM 567CM</td>
<td>Samples</td>
</tr>
<tr>
<td>LM567CN/NOPB</td>
<td>ACTIVE</td>
<td>PDIP</td>
<td>P</td>
<td>8</td>
<td>40</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU SN</td>
<td>Level-1-NA-UNLIM</td>
<td>0 to 70</td>
<td>LM 567CN</td>
<td>Samples</td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:
- **ACTIVE**: Product device recommended for new designs.
- **LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
- **NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
- **PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.
- **OBSOLETE**: TI has discontinued the production of the device.

(2) **RoHS**: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
- **RoHS Exempt**: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
- **Green**: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI’s liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.
TAPE AND REEL INFORMATION

*All dimensions are nominal.*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM567CMX/NOPB</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>330.0</td>
<td>12.4</td>
<td>6.5</td>
<td>5.4</td>
<td>2.0</td>
<td>8.0</td>
<td>12.0</td>
<td>Q1</td>
</tr>
</tbody>
</table>

**Definitions:**
- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P1: Pitch between successive cavity centers
### TAPE AND REEL BOX DIMENSIONS

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
<th>Height (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM567CMX/NOPB</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>367.0</td>
<td>367.0</td>
<td>35.0</td>
</tr>
</tbody>
</table>

*All dimensions are nominal*
NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001 variation BA.
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